# BC858CDXV6T1, BC858CDXV6T5

# **Dual General Purpose Transistor**

## **PNP** Dual

This transistor is designed for general purpose amplifier applications. It is housed in the SOT–563 which is designed for low power surface mount applications.

### Features

• These are Pb–Free Devices

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	-30	V
Collector-Base Voltage	V <sub>CBO</sub>	-30	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current – Continuous	Ι <sub>C</sub>	-100	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS

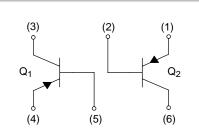
Characteristic (One Junction Heated)	Symbol	Мах	Unit
Total Device Dissipation, (Note 1) $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub>	357 2.9	mW mW/°C
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{\thetaJA}$	350	°C/W
Characteristic (Both Junctions Heated)	Symbol	Мах	Unit
Total Device Dissipation, (Note 1)			
$T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub>	500 4.0	mW mW/°C
$T_A = 25^{\circ}C$	Ρ <sub>D</sub> R <sub>θJA</sub>		

1. FR-4 @ Minimum Pad



## **ON Semiconductor®**

http://onsemi.com





SOT-563 CASE 463A PLASTIC

### MARKING DIAGRAMS



3L = Device Code

M = Date Code

.

= Pb–Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
BC858CDXV6T1	SOT-563	4000/Tape & Reel
BC858CDXV6T1G	SOT-563 (Pb-Free)	4000/Tape & Reel
BC858CDXV6T5	SOT-563	8000/Tape & Reel
BC858CDXV6T5G	SOT-563 (Pb-Free)	8000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

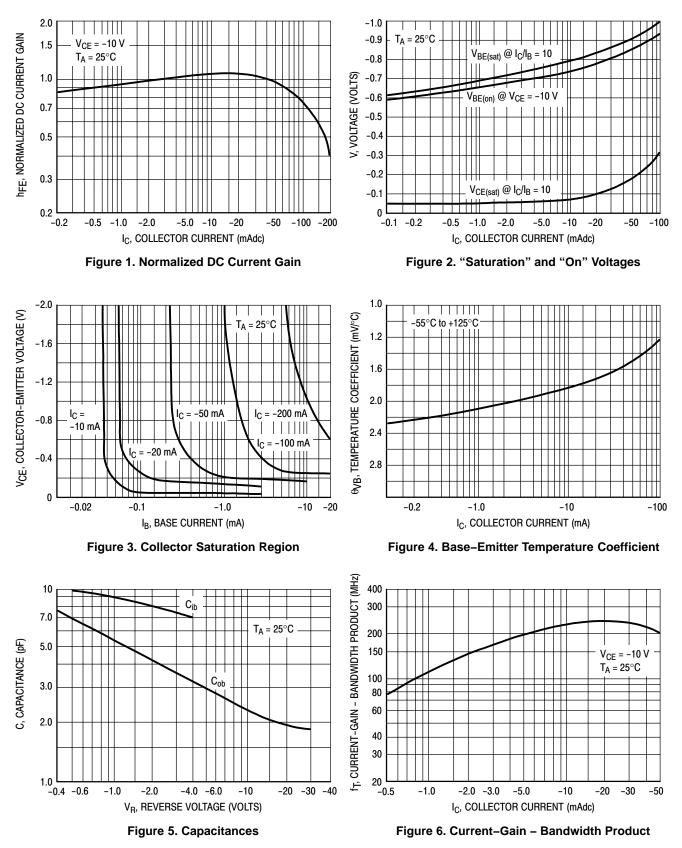
# BC858CDXV6T1, BC858CDXV6T5

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				•	
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = –10 mA)	V <sub>(BR)CEO</sub>	-30	_	_	V
Collector – Emitter Breakdown Voltage $(I_C = -10 \ \mu A, \ V_{EB} = 0)$	V <sub>(BR)CES</sub>	-30	-	_	V
Collector – Base Breakdown Voltage $(I_C = -10 \ \mu A)$	V <sub>(BR)CBO</sub>	-30	-	_	V
Emitter – Base Breakdown Voltage $(I_E = -1.0 \ \mu A)$	V <sub>(BR)EBO</sub>	-5.0	-	_	V
Collector Cutoff Current (V <sub>CB</sub> = $-30$ V) (V <sub>CB</sub> = $-30$ V, T <sub>A</sub> = $150^{\circ}$ C)	I <sub>CBO</sub>			-15 -4.0	nA μA
ON CHARACTERISTICS			•		
DC Current Gain $(I_C = -10 \ \mu\text{A}, \ V_{CE} = -5.0 \ \text{V})$ $(I_C = -2.0 \ \text{mA}, \ V_{CE} = -5.0 \ \text{V})$	hFE	420	270 520	800	_
Collector – Emitter Saturation Voltage ( $I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$ ) ( $I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$ )	V <sub>CE(sat)</sub>			-0.3 -0.65	V
Base – Emitter Saturation Voltage $(I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA})$ $(I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA})$	V <sub>BE(sat)</sub>		-0.7 -0.9		V
Base – Emitter On Voltage $(I_{C} = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V})$ $(I_{C} = -10 \text{ mA}, V_{CE} = -5.0 \text{ V})$	V <sub>BE(on)</sub>	-0.6 -		-0.75 -0.82	V
SMALL-SIGNAL CHARACTERISTICS	·		•		•
Current-Gain – Bandwidth Product ( $I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ Vdc}, f = 100 \text{ MHz}$ )	f <sub>T</sub>	100	-	_	MHz
Output Capacitance ( $V_{CB} = -10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$ )	C <sub>ob</sub>	-	-	4.5	pF
Noise Figure (I <sub>C</sub> = $-0.2$ mA, V <sub>CE</sub> = $-5.0$ Vdc, R <sub>S</sub> = $2.0$ kΩ, f = $1.0$ kHz, BW = $200$ Hz)	NF	-	-	10	dB

### BC858CDXV6T1, BC858CDXV6T5

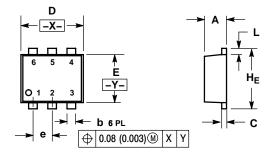
### **TYPICAL CHARACTERISTICS**



### BC858CDXV6T1, BC858CDXV6T5

### PACKAGE DIMENSIONS

SOT-563, 6 LEAD CASE 463A-01 ISSUE F



NOTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982

CONTROLLING DIMENSION: MILLIMETERS

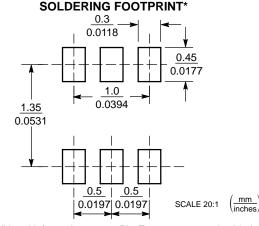
MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS 3.

IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
Ε	1.10	1.20	1.30	0.043	0.047	0.051
е	0.5 BSC			0.02 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.062	0.066

STYLE 1: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2

5. BASE 2 6. COLLECTOR 1



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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